

Small Signal Switching Diodes

COACHIP
SMB Diodes Specialist

CDSH3-222N/-G/222P-G

Reverse Voltage: 80 Volts

Pd: 150mW

RoHS Device



Features

Designed for mounting on small surface.

High speed switching.

High mounting capability, strong surge withstand, high reliability.

Mechanical data

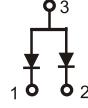
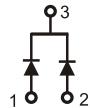
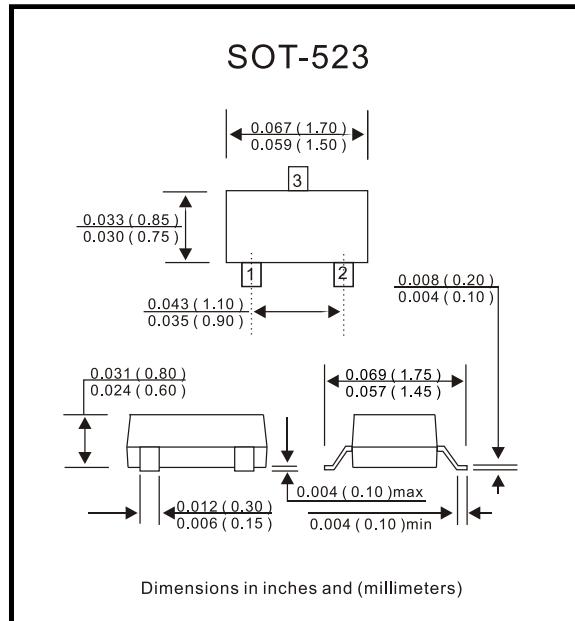
Case:SOT-523, molded plastic.

Terminals: Solder plated, solderable per MIL-STD-750, method 208.

Approx. weight: 0.002 gram

CDSH3-222N-G

CDSV3-222P-G



Maximum Ratings and Electrical Characteristics (at Ta = 25°C unless otherwise noted)

Parameter	Condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V _{RRM}	80	V
Reverse voltage		V _R	80	V
Forward continue current		I _{FM}	300	mA
Surge peak forward current	T = 1.0 uS	I _{FSM}	4	A
Power dissipation		P _d	150	mW
Maximum forward voltage	@ IF = 100 mA	V _F	1.2	V
Maximum reverse current	@ VR = 70V	I _R	0.1	uA
Max reverse recovery time	IF=IR=5mA, R=100 ohms	T _{rr}	4	nS
Maximum diode capacitnace	VR=6V, f=1MHz	C _T	3.5	pF
Max. operation junction temperature		T _j	150	°C
Storage temperature		T _{STG}	-55 to +150	°C

Rev. A

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RATING AND CHARACTERISTIC CURVES (CDSH3-222N-G/222P-G)

Fig. 1 - Forward characteristics(P Type)

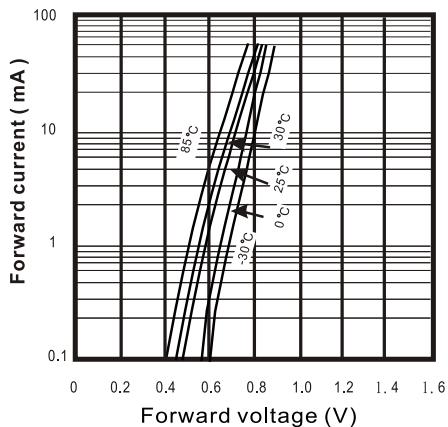


Fig. 2 - Reverse characteristics(P Type)

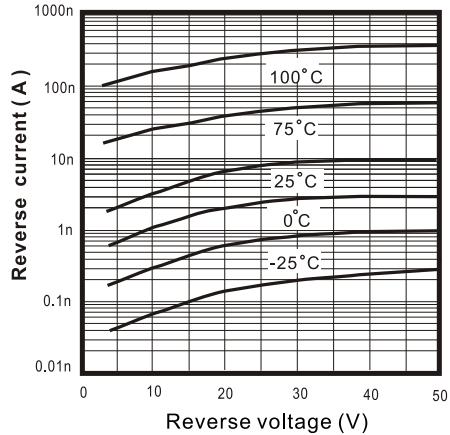


Fig. 3 - Forward characteristics(N Type)

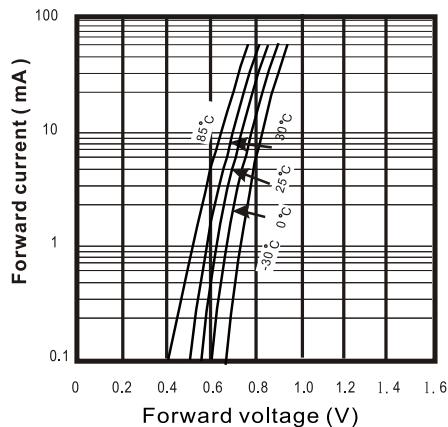


Fig. 4 - Reverse characteristics(N Type)

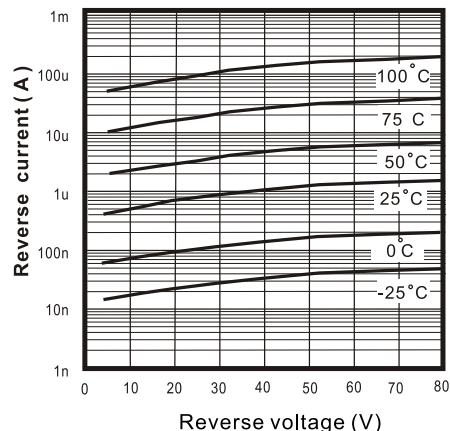


Fig. 5 - Capacitance between terminals characteristics

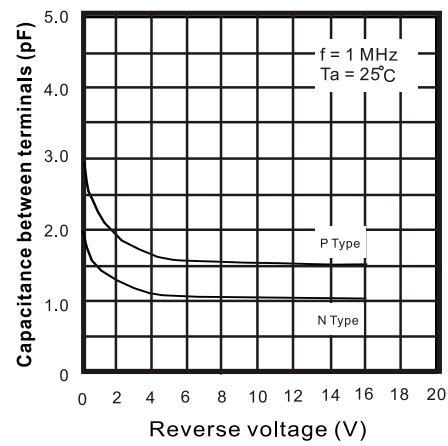


Fig. 6 - Power attenuation curve

